

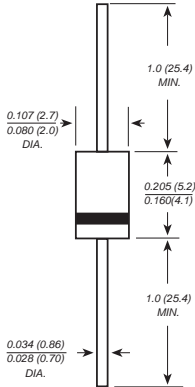


# SR120 THRU SR1200

## SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 1.0 Ampere

### DO-41



Dimensions in inches and (millimeters)

### FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:  
250°C/10 seconds, 0.375" (9.5mm) lead length,  
5 lbs. (2.3kg) tension

### MECHANICAL DATA

**Case:** JEDEC DO-41 molded plastic body  
**Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026  
**Polarity:** Color band denotes cathode end  
**Mounting Position:** Any  
**Weight:** 0.012 ounce, 0.33 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.  
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	SR 120	SR 130	SR 140	SR 150	SR 160	SR 170	SR 180	SR 190	SR 1A0	SR 1150	SR 1200	UNITS	
Maximum repetitive peak reverse voltage	$V_{RRM}$	20	30	40	50	60	70	80	90	100	150	200	VOLTS	
Maximum RMS voltage	$V_{RMS}$	14	21	28	35	42	49	56	63	70	105	140	VOLTS	
Maximum DC blocking voltage	$V_{DC}$	20	30	40	50	60	70	80	90	100	150	200	VOLTS	
Maximum average forward rectified current 0.375" (9.5mm) lead length (see fig.1)	$I_{AV}$	1.0											Amp	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	40.0											Amps	
Maximum instantaneous forward voltage at 1.0A	$V_F$	0.55		0.70		0.85			0.95			Volts		
Maximum DC reverse current at rated DC blocking voltage	$I_R$	0.5					0.2			mA				
		10.0					5.0			2.0				
Typical junction capacitance (NOTE 1)	$C_J$	110			80								pF	
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0											°C/W	
Operating junction temperature range	$T_J$	-65 to +125					-65 to +150							°C
Storage temperature range	$T_{STG}$	-65 to +150											°C	

**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

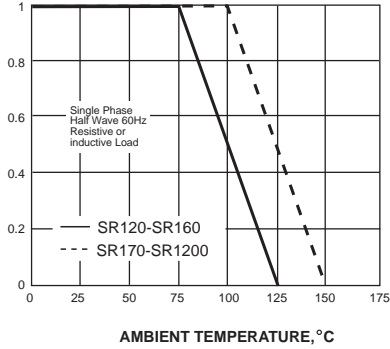
2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

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# RATINGS AND CHARACTERISTIC CURVES SR120 THRU SR1200

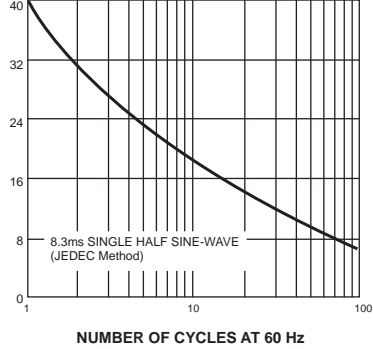
AVERAGE FORWARD RECTIFIED CURRENT,  
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



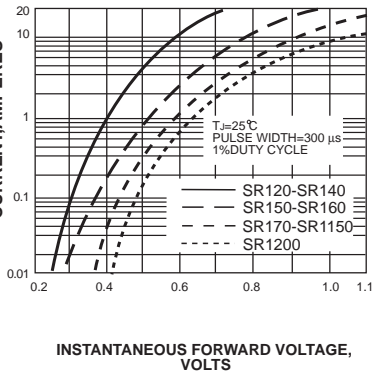
PEAK FORWARD SURGE CURRENT,  
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



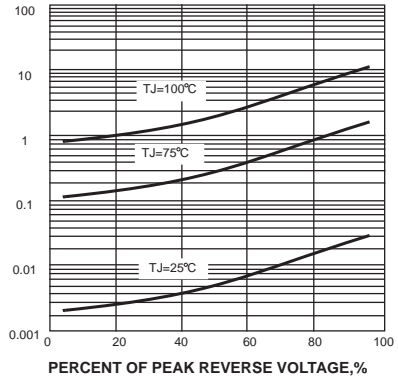
INSTANTANEOUS FORWARD CURRENT, AMPERES

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



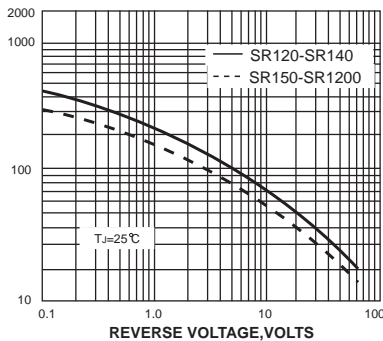
INSTANTANEOUS REVERSE CURRENT, MILLIAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

